



SST502 Series

Vishay Siliconix

Current Regulator Diodes— $P_{OV(min)}$ 45 V

SST502
SST503

SST504
SST505

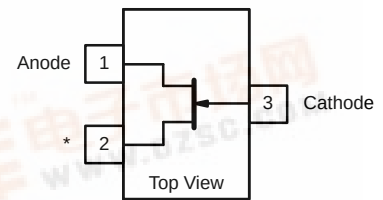
SST506
SST507

SST508
SST509

SST510
SST511

PRODUCT SUMMARY					
Part Number	Typ I_F (mA)	Marking		Part Number	Typ I_F (mA)
SST502	0.43	L2		SST507	1.80
SST503	0.56	L3		SST508	2.40
SST504	0.75	L4		SST509	3.00
SST505	1.00	L5		SST510	3.60
SST506	1.40	L6		SST511	4.70

TO-236
(SOT-23)



*Short lead #2 to Cathode (lead #3) via circuit board trace.

FEATURES

- Surface-Mount Package
- Guaranteed $\pm 20\%$ Tolerance
- Operation from 1 V (SST502, 3) to 45 V
- Good Temperature Stability

BENEFITS

- Simple Series Circuitry, No Separate Voltage Source
- Tight Guaranteed Circuit Performance
- Excellent Performance in Low-Voltage/Battery Circuits and High-Voltage Spike Protection
- High Circuit Stability vs. Temperature

APPLICATIONS

- Constant-Current Supply
- Current-Limiting
- Timing Circuits

DESCRIPTION

The SST502 series is a family of $\pm 20\%$ range current regulators designed for demanding applications in test equipment and instrumentation. These devices utilize the JFET techniques to produce a device which is extremely simple to operate.

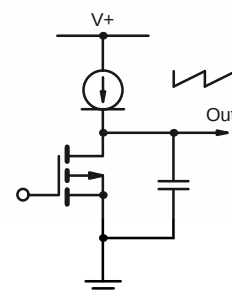
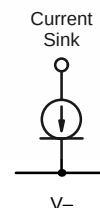
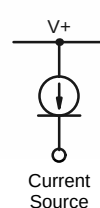
With nominal current ranges from 0.43 mA to 4.7 mA, the SST502 series will meet a wide array of design requirements.

The low-cost TO-236 surface-mount package ensures a cost-effective design solution.

SCHEMATIC DIAGRAM



APPLICATIONS



Linear Ramp Generator

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ABSOLUTE MAXIMUM RATINGS

Peak Operating Voltage 45 V
Reverse Current 50 mA
Storage Temperature -55 to 150°C

Power Dissipation^a 350 mW

Notes:

a. Derate 2.8 mW/°C above 25°C

SPECIFICATIONS^a

Parameter	Symbol	Test Conditions	Limits			Unit
			Min	Typ ^b	Max	
Peak Operating Voltage	P _{OV}	I _F = 1.1 I _{F(max)} ^c	45	55		V
Reverse Voltage	V _R	I _R = 1 mA		0.8		
Capacitance	C _F	V _F = 25 V, f = 1 MHz		1.5		pF

	Regulator Current ^d (I _F)			Dynamic Impedance ^e (Z _d)		Knee Impedance (Z _k)	Limiting Voltage ^f (V _L)		Temperature Coefficient (θ ₁)
	V _F = 25 V			V _F = 25 V		V _F = 6 V	I _F = 0.8 I _{F(min)}		V _F = 25 V 0°C ≤ T _A ≤ 100°C
Part Number	mA			MΩ		MΩ	V		%/°C
	Min	Nom	Max	Min	Typ ^b	Typ ^b	Max	Typ ^b	Typ ^b
SST502	0.344	0.43	0.516	1.0	2.7	0.7	1.5	0.6	-0.08%
SST503	0.448	0.56	0.672	0.7	2.0	0.5	1.7	0.7	-0.12%
SST504	0.600	0.75	0.900	0.5	1.5	0.4	1.9	0.8	-0.16%
SST505	0.800	1.00	1.200	0.4	1.0	0.3	2.1	0.9	-0.20%
SST506	1.120	1.40	1.680	0.3	0.8	0.2	2.5	1.1	-0.24%
SST507	1.440	1.80	2.160	0.2	0.6	0.12	2.8	1.3	-0.28%
SST508	1.900	2.40	2.900	0.1	0.4	0.08	3.1	1.5	-0.31%
SST509	2.400	3.00	3.600	0.09	0.3	0.06	3.5	1.7	-0.34%
SST510	2.900	3.60	4.300	0.08	0.3	0.04	3.9	1.9	-0.37%
SST511	3.800	4.70	5.600	0.07	0.2	0.03	4.2	2.1	-0.40%

Notes:

- T_A = 25°C unless otherwise noted.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- Max V_F where I_F = 1.1 I_{F(max)} is guaranteed.
- Pulse test—steady state currents may vary.
- Pulse test—steady state impedances may vary.
- Min V_F required to insure I_F = 0.8 I_{F(min)}.

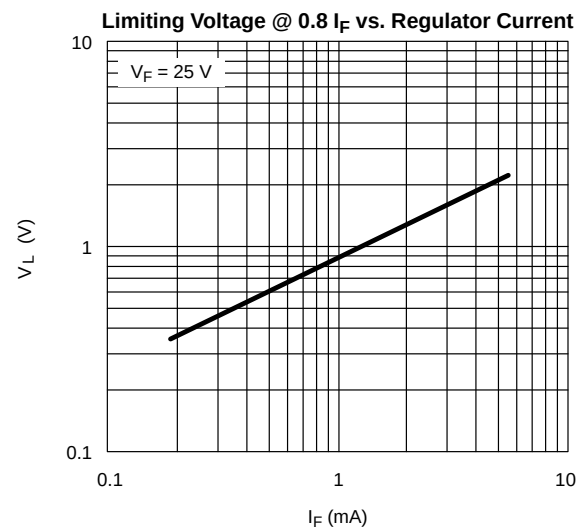
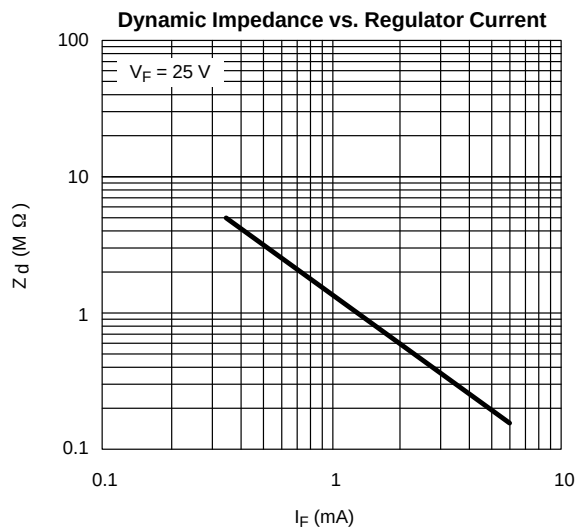
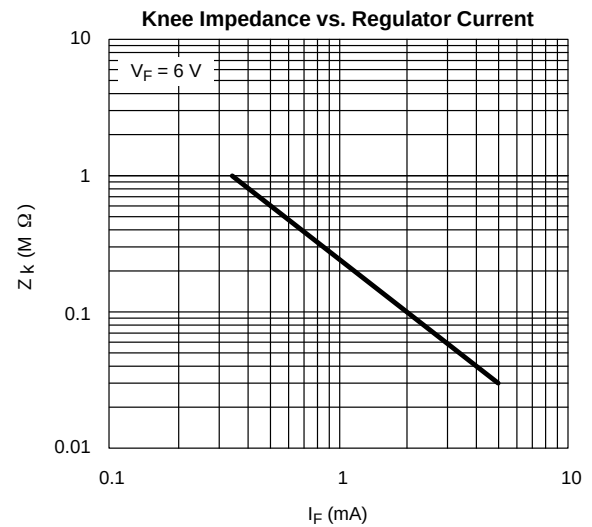
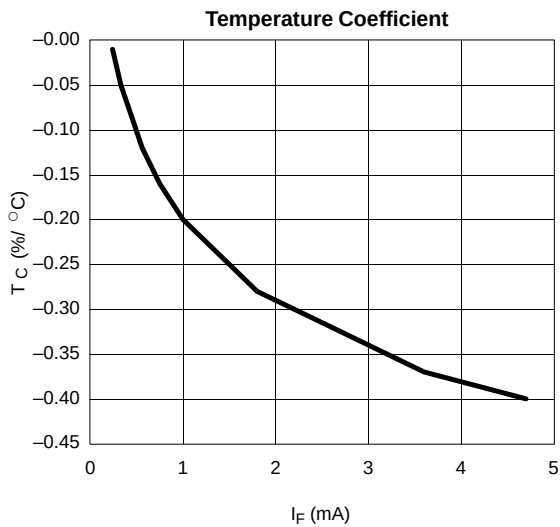
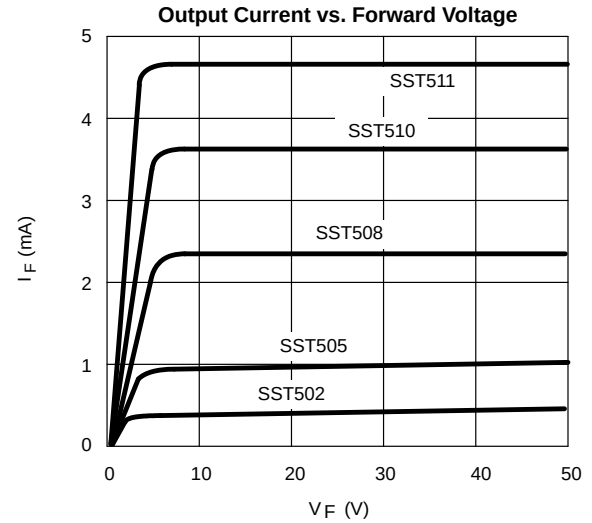
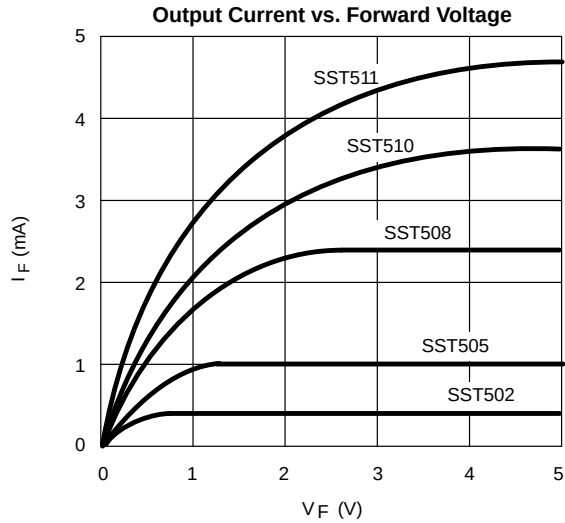
NPA



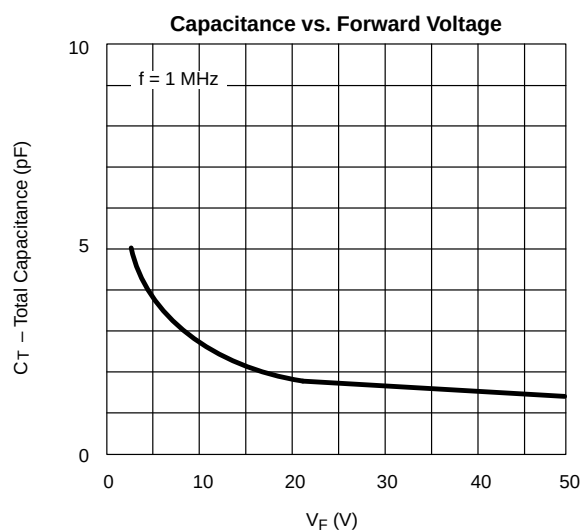
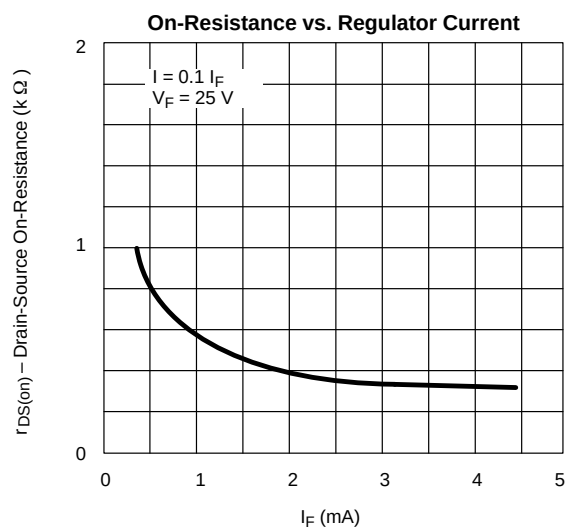
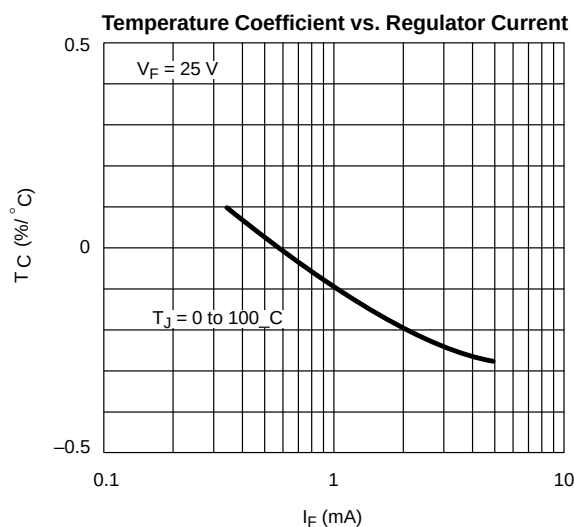
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TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



CURRENT REGULATOR DIODE V-1 CHARACTERISTIC

